

ZXTP25020DFL 20V, SOT23, PNP low power transistor

Summary

 $BV_{CEO} > -20V$

 $BV_{ECO} > -4V$

 $I_{C(cont)} = 1.5A$

V_{CE(sat)} < 85 mV @ 1A

 $R_{CE(sat)} = 54m\Omega$

 $P_D = 350 \text{mW}$

Complementary part number ZXTN25020DFL



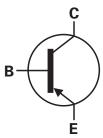
Advanced process capability has been used to achieve high current gain hold up making this device ideal for applications requiring high pulse currents.

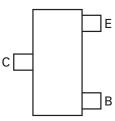
Features

- · High peak current
- · Low saturation voltage

Applications

- · DC-DC converters
- · MOSFET and IGBT gate driving





Pinout - top view

Ordering information

| Device | Reel size (inches) | Tape width (mm) | Quantity per reel |
|----------------|-----------------------|--------------------|-------------------|
| ZXTP25020DFLTA | 7 | 8 | 3000 |

Device marking

1F2

Absolute maximum ratings

| Parameter | Symbol | Limit | Unit |
|--|-----------------------------------|------------|-------|
| Collector-base voltage | V _{CBO} | -25 | V |
| Collector-emitter voltage (forward blocking) | V _{CEO} | -20 | V |
| Emitter-collector voltage (reverse blocking) | V _{ECO} | -4 | V |
| Emitter-base voltage | V _{EBO} | -7 | V |
| Continuous collector current | I _C | -1.5 | Α |
| Base current | I _B | -500 | mA |
| Peak pulse current | I _{CM} | -6 | А |
| Power dissipation at T _{amb} =25°C ^(a) | P _D | 350 | mW |
| Linear derating factor | | 2.8 | mW/°C |
| Operating and storage temperature range | T _j , T _{stg} | -55 to 150 | °C |

Thermal resistance

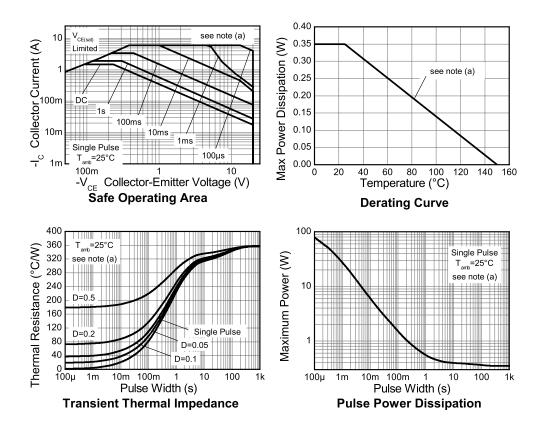
| Parameter | Symbol | Limit | Unit |
|------------------------------------|-----------------|-------|------|
| Junction to ambient ^(a) | $R_{\Theta JA}$ | 357 | °C/W |

NOTES:

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⁽a) For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

Characteristics



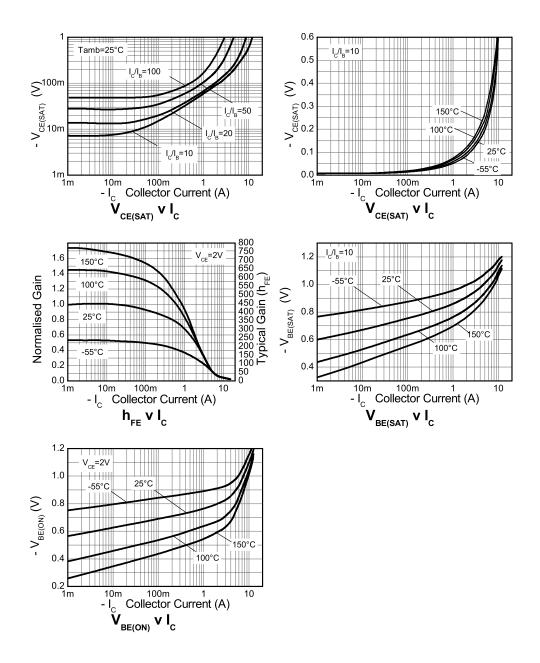
Electrical characteristics (at $T_{amb} = 25$ °C unless otherwise stated)

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions |
|--|----------------------|------|------|------|------|---|
| Collector-base breakdown voltage | BV _{CBO} | -25 | -55 | | V | $I_C = -100 \mu A$ |
| Collector-emitter breakdown voltage (base open) | BV _{CEO} | -20 | -45 | | V | I _C = -10mA ^(*) |
| Emitter-base breakdown voltage | BV _{EBO} | -7 | -8.3 | | V | I _E = -100μA |
| Emitter-collector breakdown voltage (reverse blocking) | BV _{ECO} | -4 | -8.5 | | V | I _E = -100uA ^(*) |
| Collector cut-off current | Ісво | | <-1 | -50 | nA | V _{CB} = -20V |
| | | | | -20 | μΑ | $V_{CB} = -20V, T_{amb} = 100^{\circ}C$ |
| Emitter cut-off current | I _{EBO} | | <-1 | -50 | nA | V _{EB} = -5.6V |
| Collector-emitter saturation voltage | V _{CE(sat)} | | -65 | -85 | mV | $I_C = -1A$, $I_B = -100 \text{mA}^{(*)}$ |
| Voitage | | | -160 | -225 | mV | $I_C = -1A, I_B = -10mA^{(*)}$ |
| | | | 150 | -195 | mV | $I_C = -1.5A$, $I_B = -30mA^{(*)}$ |
| | | | -210 | -275 | mV | $I_C = -2A$, $I_B = -40 \text{mA}^{(*)}$ |
| | | | -215 | 260 | mV | $I_C = -4A$, $I_B = -400 \text{mA}^{(*)}$ |
| Base-emitter saturation voltage | V _{BE(sat)} | | -845 | -950 | mV | $I_C = -1.5A$, $I_B = -30mA^{(*)}$ |
| Base-emitter turn-on voltage | V _{BE(on)} | | -785 | -900 | mV | $I_C = -1.5A, V_{CE} = -2V^{(*)}$ |
| Static forward current transfer | h _{FE} | 300 | 450 | 900 | | $I_C = -10 \text{mA}, V_{CE} = -2V^{(*)}$ |
| ratio | | 160 | 250 | | | $I_C = -1.5A, V_{CE} = -2V^{(*)}$ |
| | | 60 | 90 | | | $I_C = -4A$, $V_{CE} = -2V^{(*)}$ |
| | | | 15 | | | $I_C = -10A$, $V_{CE} = -2V^{(*)}$ |
| Transition frequency | f _T | | 290 | | MHz | $I_C = -50 \text{mA}, V_{CE} = -10 \text{V}$ f = 50MHz |
| Output capacitance | C _{obo} | | 21 | 30 | pF | V _{CB} = -10V, f = 1MHz ^(*) |
| Delay time | t _(d) | | 14.2 | | | $V_{CC} = -10V. I_C = -1A, I_{B1}$ |
| Rise time | t _(r) | | 16.3 | | | = I _{B2} = -50mA. |
| Storage time | t _(s) | | 186 | | | |
| Fall time | t _(f) | | 32.7 | | | |

NOTES

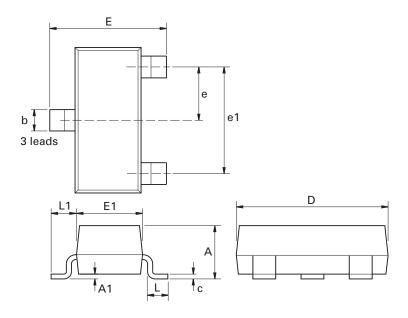
(*) Measured under pulsed conditions. Pulse width $\leq 300 \mu s$; duty cycle $\leq 2\%$.

Typical characteristics



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Package outline - SOT23



| Dim. | Millin | neters | Inc | hes | Dim. | Millimeters | | Inches | |
|------|--------|--------|--------|-------|------|-------------|------|-----------|-------|
| | Min. | Max. | Min. | Max. | | Min. | Max. | Max. | Max. |
| Α | - | 1.12 | - | 0.044 | e1 | 1.90 NOM | | 0.075 NOM | |
| A1 | 0.01 | 0.10 | 0.0004 | 0.004 | Е | 2.10 | 2.64 | 0.083 | 0.104 |
| b | 0.30 | 0.50 | 0.012 | 0.020 | E1 | 1.20 | 1.40 | 0.047 | 0.055 |
| С | 0.085 | 0.120 | 0.003 | 0.008 | L | 0.25 | 0.62 | 0.018 | 0.024 |
| D | 2.80 | 3.04 | 0.110 | 0.120 | L1 | 0.45 | 0.62 | 0.018 | 0.024 |
| е | 0.95 | NOM | 0.0375 | NOM | - | - | - | - | - |

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

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| Europe | Americas | Asia Pacific | Corporate Headquarters |
|---|---|--|--|
| Zetex GmbH Kustermann-park Balanstraße 59 D-81541 München Germany | Zetex Inc 700 Veterans Memorial Highway Hauppauge, NY 11788 USA | Zetex (Asia Ltd) 3701-04 Metroplaza Tower 1 Hing Fong Road, Kwai Fong Hong Kong | Zetex Semiconductors plc Zetex Technology Park, Chadderton Oldham, OL9 9LL United Kingdom |
| Telefon: (49) 89 45 49 49 0 Fax: (49) 89 45 49 49 49 europe.sales@zetex.com | Telephone: (1) 631 360 2222 Fax: (1) 631 360 8222 usa.sales@zetex.com | Telephone: (852) 26100 611 Fax: (852) 24250 494 asia.sales@zetex.com | Telephone: (44) 161 622 4444 Fax: (44) 161 622 4446 hq@zetex.com |

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